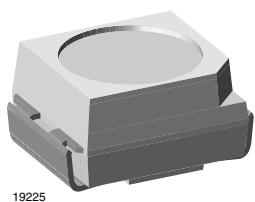


High Intensity SMD LED



19225

FEATURES

- SMD LED with exceptional brightness
- Luminous intensity categorized
- Compatible with automatic placement equipment
- EIA and ICE standard package
- Compatible with IR Reflow, vapor phase and wave solder processes according to CECC 00802 and J-STD-020C
- Available in 8 mm tape
- Low profile package
- Non-diffused lens: excellent for coupling to light pipes and backlighting
- Low power consumption
- Luminous intensity ratio in one packaging unit $I_{Vmax}/I_{Vmin} \leq 1.6$
- Lead (Pb)-free device-RoHS compliant
- Preconditioning: acc. to JEDEC Level 2a
- ESD-withstand voltage up to 1 kV according to JESD22-A114-B



e3

DESCRIPTION

This device has been designed to meet the increasing demand for InGaN technology.

The package of the VLMTG31.. is the PLCC-2.

It consists of a lead frame which is embedded in a white thermoplastic. The reflector inside this package is filled up with clear epoxy.

APPLICATIONS

- Automotive: Backlighting in dashboards and switches
- Telecommunication: Indicator and backlighting in telephone and fax
- Indicator and backlight for audio and video equipment
- Indicator and backlight in office equipment
- Flat backlight for LCDs, switches and symbols
- General use

PARTS TABLE

PART	COLOR, LUMINOUS INTENSITY	ANGLE OF HALF INTENSITY ($\pm \varphi$)	TECHNOLOGY
VLMTG31N2S1-GS08	True Green, $I_V = (35.5$ to $224)$ mcd	60°	InGaN on SiC
VLMTG31N2S1-GS18	True Green, $I_V = (35.5$ to $224)$ mcd	60°	InGaN on SiC
VLMTG31Q1R2-GS08	True Green, $I_V = (71$ to $180)$ mcd	60°	InGaN on SiC
VLMTG31Q1R2-GS018	True Green, $I_V = (71$ to $180)$ mcd	60°	InGaN on SiC

ABSOLUTE MAXIMUM RATINGS¹⁾ VLMTG31..

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage ²⁾		V _R	5	V
DC Forward current	T _{amb} ≤ 80 °C	I _F	20	mA
Surge forward current	t _p ≤ 10 µs	I _{FSM}	0.2	A
Power dissipation		P _V	84	mW
Junction temperature		T _j	110	°C
Operating temperature range		T _{amb}	- 40 to + 100	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
Thermal resistance junction/ambient	mounted on PC board (pad size > 16 mm ²)	R _{thJA}	350	K/W

Note:

1) T_{amb} = 25 °C unless otherwise specified

2) Driving LED in reverse direction is suitable for short term application

OPTICAL AND ELECTRICAL CHARACTERISTICS¹⁾ TRUE GREEN VLMTG31..

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP	MAX	UNIT
Luminous intensity ²⁾	I _F = 10 mA	VLMTG31N2S1	I _V	35.5		224	mcd
		VLMTG31Q1R2	I _V	71		180	mcd
Dominant wavelength	I _F = 10 mA		λ _d	521		541	nm
Peak wavelength	I _F = 10 mA		λ _p		522		nm
Angle of half intensity	I _F = 10 mA		φ		± 60		deg
Forward voltage	I _F = 20 mA		V _F		3.2	4.2	V
Reverse voltage	I _R = 10 µA		V _R	5			V
Temperature coefficient of V _F	I _F = 10 mA		TC _V		- 3.5		mV/K
Temperature coefficient of I _V	I _F = 10 mA		TC _I		- 0.3		%/K

Note:

1) T_{amb} = 25 °C unless otherwise specified2) in one Packing Unit I_{Vmax}/I_{Vmin} ≤ 1.6

LUMINOUS INTENSITY CLASSIFICATION			
GROUP	LIGHT INTENSITY [MCD]		
STANDARD	OPTIONAL	MIN	MAX
N	1	-	-
	2	35.5	45
P	1	45	56
	2	56	71
Q	1	71	90
	2	90	112
R	1	112	140
	2	140	180
S	1	180	224
	2	-	-

Note:

Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of ± 11 %.

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one reel.

In order to ensure availability, single wavelength groups will not be orderable.

COLOR CLASSIFICATION

GROUP	TRUE GREEN	
	DOM. WAVELENGTH (NM)	
	MIN.	MAX.
4	521	529
5	527	535
6	533	541

Note:

Wavelengths are tested at a current pulse duration of 25 ms and an accuracy of ± 1 nm.

CROSSING TABLE

VISHAY	OSRAM
VLMTG31N2S1	LTT673-N2S1
VLMTG31Q1R2	LTT673-Q1R2

TYPICAL CHARACTERISTICS

$T_{amb} = 25^{\circ}C$ unless otherwise specified

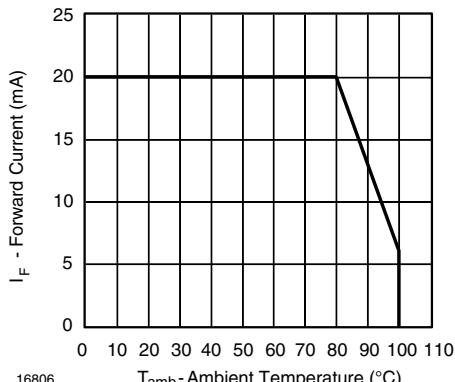


Figure 1. Forward Current vs. Ambient Temperature

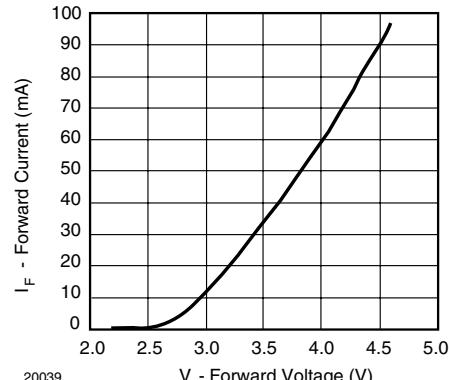


Figure 4. Forward Current vs. Forward Voltage

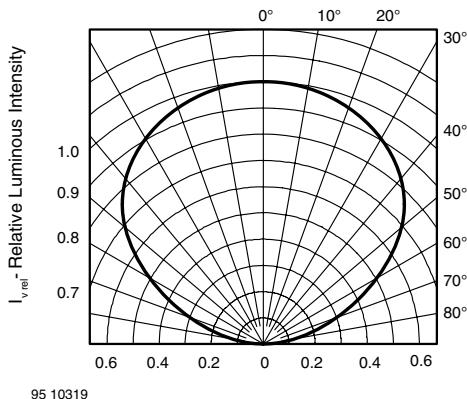


Figure 2. Relative Luminous Intensity

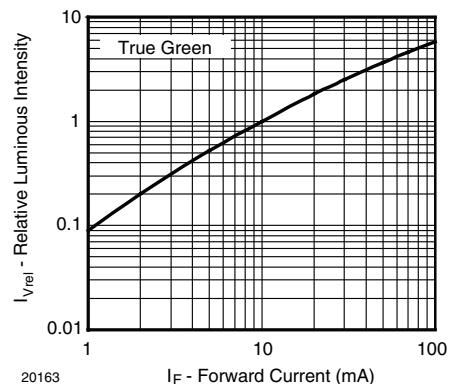


Figure 5. Specific Luminous Flux vs. Forward Current

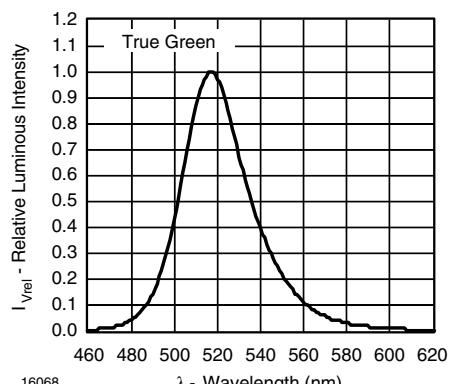


Figure 3. Relative Intensity vs. Wavelength

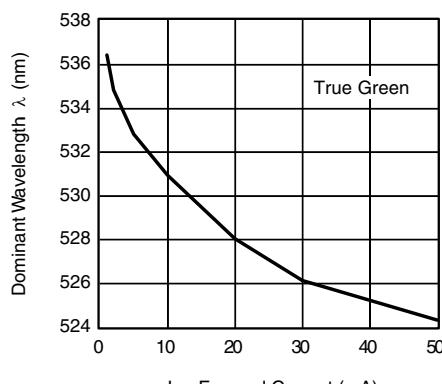
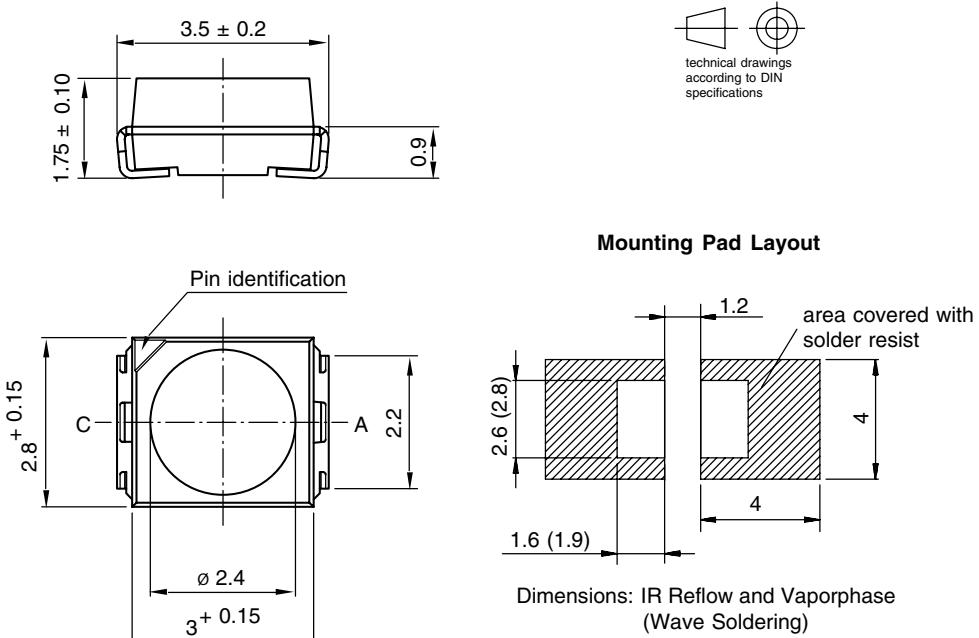


Figure 6. Dominant Wavelength vs. Forward Current

PACKAGE DIMENSIONS IN MM

METHOD OF TAPING / POLARITY AND TAPE AND REEL
SMD LED (VLM3 - SERIES)

Vishay's LEDs in SMD packages are available in an antistatic 8 mm blister tape (in accordance with DIN IEC 40 (CO) 564) for automatic component insertion. The blister tape is a plastic strip with impressed component cavities, covered by a top tape.

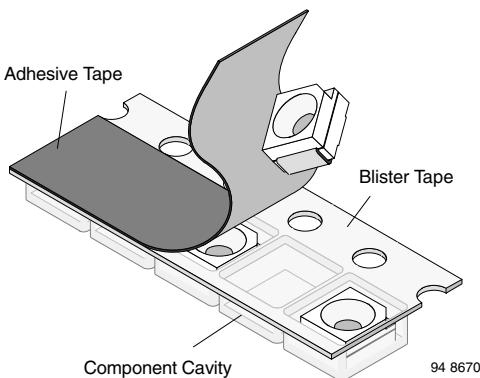
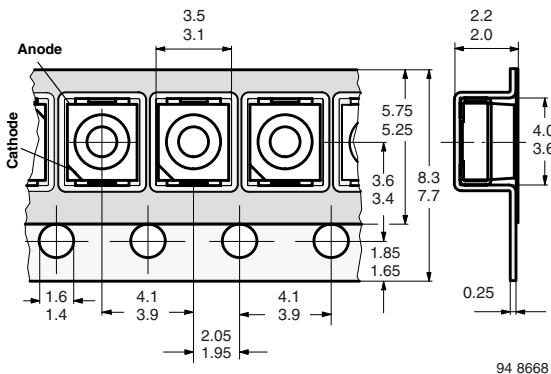

TAPING OF VLM.3..


Figure 7. Tape dimensions in mm for PLCC-2

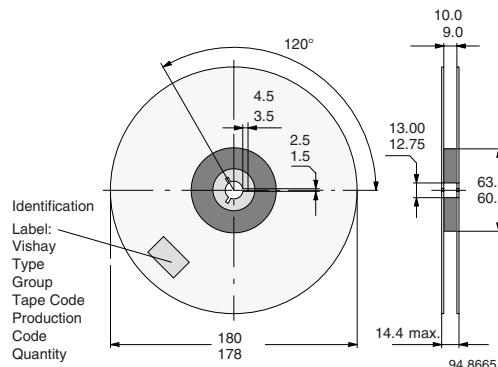
**REEL PACKAGE DIMENSION IN MM FOR SMD LEDs, TAPE OPTION GS08
(= 1500 PCS.)**


Figure 8. Reel dimensions - GS08

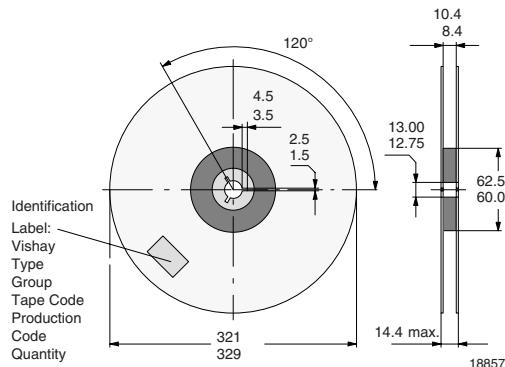
**REEL PACKAGE DIMENSION IN MM FOR SMD LEDs, TAPE OPTION GS18
(= 8000 PCS.) PREFERRED**


Figure 9. Reel dimensions - GS18

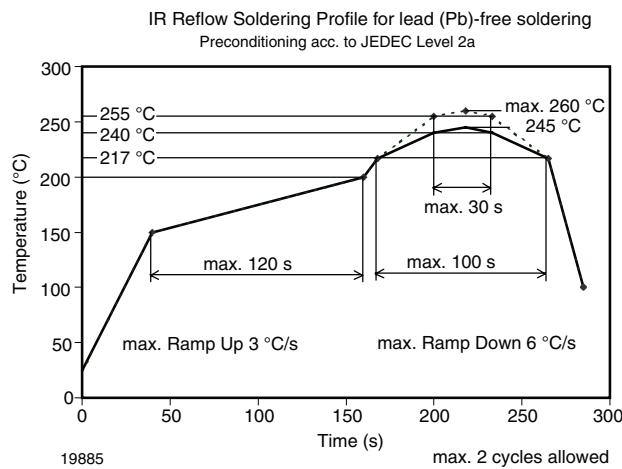
SOLDERING PROFILE

Figure 10. Vishay Lead (Pb)-free Reflow Soldering Profile
(acc. to J-STD-020C)

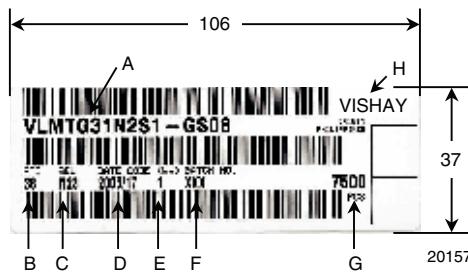
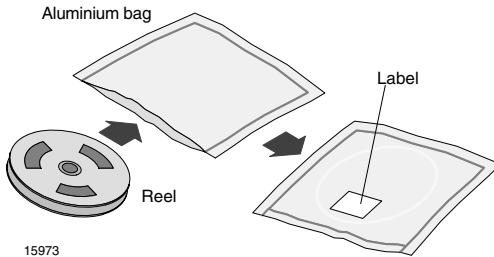
BARCODE-PRODUCT-LABEL

Figure 11. Double wave soldering of opto devices (all packages)

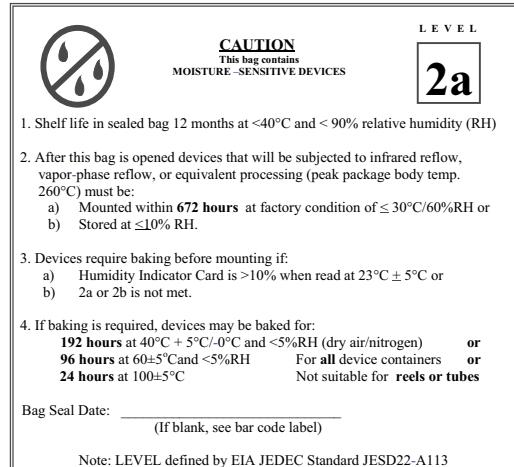
A) Type of component
 B) Manufacturing Plant
 C) SEL - Selection Code (Bin):
 e.g.: N2 = Code for Luminous Intensity Group
 3 = Code for Color Group
 D) Date Code year/week
 E) Day Code (e.g. 1: Monday)
 F) Batch No.
 G) Total quantity
 H) Company Code

DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



15973



19786

Example of JESD22-A112 Level 2a label

FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminium bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 672 hours under these conditions moisture content will be too high for reflow soldering.

In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 hours at 40 °C + 5 °C/- 0 °C and < 5 % RH (dry air/ nitrogen) or

96 hours at 60 °C + 5 °C and < 5 % RH for all device containers or

24 hours at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC Standard JESD22-A112 Level 2a label is included on all dry bags.

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the Antistatic Shielding Bag. Electro-Static Sensitive Devices warning labels are on the packaging.

VISHAY SEMICONDUCTORS STANDARD BAR-CODE LABELS

The Vishay Semiconductors standard bar-code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.

Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany